Sintering and Microwave Dielectric Properties of $Ba_2Ti_9O_{20}$ Ceramics Prepared by Precursor Method

Je-Hong Sung, Joon-Hyung Lee, Jeong-Joo Kim, Hee Young Lee, and Sang-Hee Cho

Department of Inorganic Materials Engineering, Kyungpook National University, Daegu 702-701, Korea *School of Metallurgical and Materials Engineering, Yeungnam University, Kyongsan 712-749, Korea (Received March 19, 2003; Accepted March 29, 2003)

ABSTRACTS

The phase development process of $Ba_2Ti_9O_{20}$ ceramics is not clearly known and frequently accompanies second phases which deteriorate dielectric properties. In synthesizing $Ba_2Ti_9O_{20}$ ceramics, in order to trace the reaction sequence during conventional solid-state reaction in BaO- TiO_2 system, different barium sources of $BaCO_3$ and $BaTiO_3$ precursor were used as starting materials. From the analysis of XRD patterns, different secondary phases could be identified depending on the barium source used, which might mean that the equilibrium phases in BaO- TiO_2 system are very difficult to be synthesized. Because the $BaTiO_3$ precursor provides short diffusion paths of ions, the system revealed less secondary phases during solid state reaction. In synthesizing BaO- xSm_2O_3 -4.5 TiO_2 system using different barium sources, different secondary phases were developed also. Microstructure and dielectric properties were examined and discussed in terms of secondary phase development.

Key words: Ba, Ti, O, Precursor, Microwave, Dielectric, Secondary phase

1. Introduction

ith recent progress in microwave telecommunication and satellite broadcasting industries, various microwave components such as band pass filter, duplexer and oscillator utilizing dielectric resonator are widely used in miniaturized filters and resonators. Since 1970s, microwave dielectric ceramics with dielectric constant ranging 20–40 such as Ba(Mg,Ta)O₃, Ba(Zn,Ta)O₃, BaTi₄O₉, and Ba₂Ti₉O₂₀ systems have been developed and applied successfully to many commercial units. ^{1,2)} The research and development of BaO-TiO₂ system with high dielectric performance have been followed. ³⁻⁵⁾ On the other hand, great attention has been paid on the phase development of BaO-TiO₂ system as its application to microwave dielectrics is widely made.

In this system, it was, however, found that the secondary phases which are not readily eliminated by conventional ceramic manufacturing process are developed during heat treatment. Although many successive works have been focused on the phase development, the phase development as well as the phase relations is not clearly understood to date, which signifies that the equilibrium phases are hardly obtained.

It is well known that pyrochlore phases are easily formed during solid-state reaction of Pb(Mg_{1/3}Nb_{2/3})O₃ (PMN) ceramics.⁶⁾ Once the pyrochlore phase is formed, it is not readily decomposed into the perovskite phase since the

pyrochlore phase is very stable. Therefore, the precursor method which alters the reaction sequence and leads to almost pyrochlore free material is often employed.71 The BaO-TiO2 binary system is the model case in which this kind of approach is routinely exercised since various inter $mediate \hspace{0.2cm} phases \hspace{0.2cm} of \hspace{0.2cm} Ba_4Ti_{13}O_{30} \text{,} \hspace{0.2cm} BaTi_5O_{11} \text{,} \hspace{0.2cm} BaTi_4O_9 \text{,} \hspace{0.2cm} and$ Ba₂Ti₄O₂₀ co-exist along with BaTiO₃.³⁻⁵⁾ Much interest has been taken in Ba₂Ti₉O₂₀ phase among others due to its superior microwave dielectric properties. However, it is known that Ba2Ti9O20 single phase is hardly obtained by mixed oxide method with poor densification behavior. 3-5) Therefore, the use of raw materials, i.e., BaTiO3 and TiO2 are much more advantageous to obtain the single phase of Ba₂Ti₉O₂₀ rather than BaCO₃ and TiO₂. Since a systematic phase development process and sintering behavior in BaO-TiO2 system have scarcely examined, it is necessary to compare the effect of different barium sources of BaCO₃ and BaTiO₃ for a detailed understanding of phase development.

In this study, to synthesize $Ba_2Ti_9O_{20}$ ceramics by the general solid state reaction process, different barium sources of $BaCO_3$ and $BaTiO_3$ precursor were used as starting materials. The reaction sequence during conventional solid-state reaction process and the sintering behavior were examined. Microwave dielectric permittivity was also measured. Examination on $BaO-xSm_2O_3-4.5TiO_2$ system, which is a good microwave dielectric material, was also conducted when different barium sources are used.

2. Experimental Procedures

Conventional solid-state reaction process was used for

[†]Corresponding author: Jeong-Joo Kim

E-mail: jjkim@knu.ac.kr

Tel: +82-53-950-5635 Fax: +82-53-950-5645

sample preparation. Two different synthesis methods were employed, i.e., mixed oxide method and precursor method. In the mixed oxide method, BaCO3 and TiO2 were used as raw materials, and in the precursor method, BaTiO3 and TiO₂ were used. These different methods using BaCO₃ and BaTiO₃ are denoted as BCT and BTT, respectively. BaO $xSm_{2}O_{2}-4.5TiO_{2}$ system where $x=0\sim1.25$ was also prepared using different barium sources. After wet mixing using a ball-mill, the mixture was calcined in the temperature range of 900-1100°C for 2 h. The granulated powders were then pressed into pellets under the pressure of 1.5 ton/cm². The specimens were sintered in the temperature range of 1200-1390°C for 2 h in air. The relative density of the sintered samples was measured using water immersion technique. The crystalline phases of calcined powders were determined by X-ray diffraction (XRD; Mac science, M03XHF, Yokohama, Japan). The microstructure of the sample surfaces was observed using a scanning electron microscope (SEM; JEOL, JML5400, Tokyo, Japan). The relative permittivity value of the samples in the microwave range was measured by the parallel plate method originally proposed by Hakki and Coleman⁸⁾ utilizing TE₀₁ resonant mode. The quality factor (Q×f) was measured by the open cavity resonator method9 using HP8720C network analyzer.

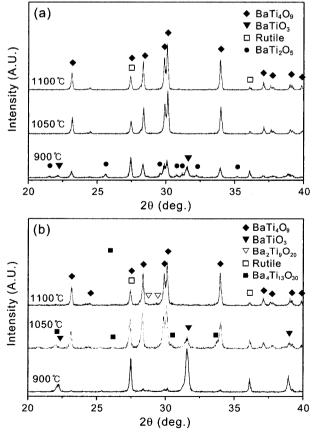


Fig. 1. X-ray diffraction patterns of (a) BCT and (b) BTT powders calcined at indicated temperature for 2 h.

3. Results and Discussion

Fig. 1 shows XRD patterns of mixed powders calcined at different temperatures for 2 h. Fig. 1(a) is for the case of powders prepared by mixed oxide method (BCT) and (b) is of the precursor method (BTT). When BCT powder was calcined at 900°C, BaTi₂O₅, rutile, and much more amount of BaTi₄O₉ phases were coexisted. Over 1050°C, BaTi₄O₉ phase was appeared as a major phase and minor peaks from rutile were also observed. When BTT powder was calcined at 900°C, BaTiO₃, TiO₂ and BaTi₄O₄ phases were coexisted. Strong diffraction intensities from the raw materials of BaTiO₃ and TiO₂ were appeared while weak intensity from BaTi₄O₉ was appeared signifying that solid state reaction is insignificant compared with BCT powder calcined at the same temperature. When the BTT powder was calcined at 1050°C, complex diffraction peaks from BaTiO₃, Ba₄Ti₁₃O₄₀, TiO₂ and BaTi₄O₂ phases were observed. In case of 1100°C, major peaks from BaTi₄O₉ and minor peaks from TiO₂ were observed. However, a trace of Ba2Ti9O20 phase was appeared. From above results, it turned out that the initial stage of solid state reaction of BCT powder showed a superiority over the case of BTT powder when both powders are calcined at the same low temperature, i.e., in case of BTT, the raw powders of BaTiO3 and TiO2 were observed which

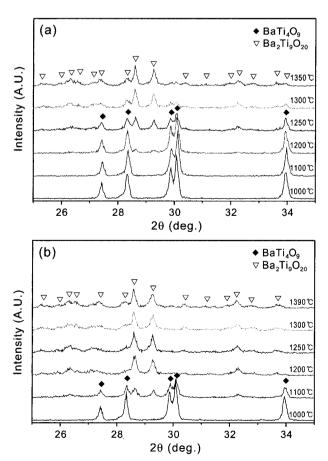


Fig. 2. X-ray diffraction patterns of (a) BCT and (b) BTT specimens sintered at indicated temperature for 2 h.

signifies the solid state reaction was hardly proceeded. However, $\mathrm{Ba_2Ti_9O_{20}}$ was observed in BTT powder at 1100°C which was not observed in BCT powder.

Fig. 2 shows the X-ray diffraction profile of the samples sintered at each temperature for 2 h. When the BCT powder was sintered at 1000°C and 1100°C, only BaTi₄O₉ phase was observed as shown in Fig. 2(a). The diffraction intensity of the Ba₂Ti₉O₂₀ phase appeared weak when the BCT powder was sintered at 1200°C and the intensity was increased drastically at 1250°C. The diffraction intensity of Ba₂Ti₉O₂₀ phase tends to increase slowly in case of the temperature over 1300°C. However, Ba₂Ti₉O₂₀ phase was not existed as a single phase at the final sintering temperature due to the remains of BaTi₄O₉ phase. Fig. 2(b) is the case of BTT powder. Only the BaTi₄O₉ phase was observed at 1000°C while the Ba₂Ti₂O₂₀ phase was drastically increased from 1100°C and almost single phase of Ba₂Ti₉O₂₀ was observed at the temperature over 1200°C. When the phase development process was compared during sintering process, more $Ba_2Ti_9O_{20}$ phase was developed in BTT powder than in BCT at lower temperatures, which means the degree of $\mathrm{Ba_2Ti_9O_{20}}$ formation retarded in BCT power compared to the case of BTT powder.

Fig. 3 shows the degree of $Ba_2Ti_9O_{20}$ formation in the sintered samples with the variation of the integrated intensity of X-ray diffraction as a function of sintering temperature. The relative amount of $Ba_2Ti_9O_{20}$ phase was estimated by

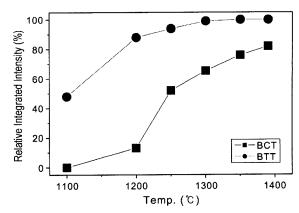


Fig. 3. The amount of $\mathrm{Ba_2Ti_9O_{20}}$ phase evaluated from relative integrated intensity of $(2\bar{2}0)$ plane as a function of sintering temperature.

the integrated intensity of $(2\overline{2}0)$ plane which reveals the biggest intensity of diffraction beam. In case of BCT, a little amount of Ba₂Ti₉O₂₀ phase was produced at 1200°C and the amount of Ba₂Ti₉O₂₀ increased sharply from 1250°C, then the increasing rate was reduced until it meets 82% of amount at 1390°C. However, in case of BTT, the amount of Ba₂Ti₉O₂₀ phase was already reached to 48% at 1100°C and became a single phase of Ba₂Ti₉O₂₀ from 1300°C.

When the BCT and BTT methods are applied to BaO- $x\text{Sm}_2\text{O}_3$ -4.5TiO₂ system (where x=0~1.25), even the detail

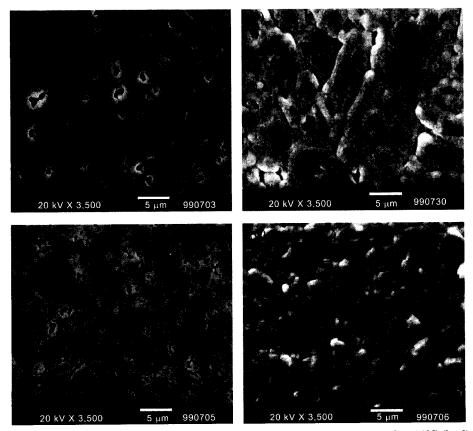


Fig. 4. SEM photographs of BCT (a, b) and BTT (c, d) specimens sintered at 1250°C (a, c) and 1390°C (b, d) for 2 h.

results are not presented in this paper, similar phase development behavior and dielectric characteristics were observed. When the samples were sintered at 1350°C for 4 h, different phases are developed by the two different processing methods of BCT and BTT. In the case where x=1, BaO-Sm₂O₃-4TiO₂ phase with the molar ratio of 1:1:4 (hereafter called 1:1:4 phase) appeared as a major phase in both the BCT and the BTT methods. However, different kinds of secondary phases were observed, i.e., BaTi₄O₉ and TiO₂ in the BCT method and Ba₂Ti₉O₂₀ in the BTT method.

The microstructure of sintered samples are represented in Fig. 4. Fig. 4(a) and (b), as BCT samples, are the cases of samples sintered at 1250°C and 1390°C for 2 h, respectively. The sample sintered at 1250°C shows small pores at grain boundaries and the porosity was 6.42±0.51%. Large and small grains in the sample coexisted and the mean grain size was 2.36±0.62 μm. The sample sintered at 1390°C has the porosity of 3.22±0.54% and the mean grain size was $8.76\pm0.58\,\mu m$. The size of pore and grain in case of the sample sintered at 1390°C was grown and the porosity decreased compared to the sample sintered at 1250°C. The pores were observed in the grain interior as well as in the grain boundaries. It is assumed that the trapped pores in the grain interior are due to the rapid grain growth. Different types of grains were seen in the microstructures of BCT samples sintered at different temperatures. We observe the surface of BaTi₄O₉ phase was smooth, while the surface of Ba₂Ti₉O₂₀ phase was rough. The difference of microstructres of two phases was also reported from the analysis of EPMA image(WDX), EDX and X-ray diffraction by Nishigaki et al. 10) In this study, EDS was also tried for the compositional analysis but the satisfactory result was not obtained because the EDS energies from Ti and Ba are similar. Fig. 4 (c) and (d), as BTT samples, are the cases of samples also sintered at 1250°C and 1390°C for 2 h, respectively. The density of the sample (c) was low with porosity of 18.62 \pm 0.78%. The density of sample (d) was high with low porosity of 1.52 \pm 0.27% which leads to the conclusion that the full densification was almost achieved. Homogeneous and fine grains with the mean grain size of 1.83 \pm 0.25 μm were observed compared to the case of BCT samples.

Fig. 5 shows the grain size distribution of BCT and BTT samples sintered at different temperatures. When BCT was sintered at 1390°C, the mean grain size was four times bigger and the grain size distribution was broader than BTT case. In BCT sample, following reaction is expected to be proceeded during sintering.

$$\mathrm{BaTi_4O_9} + \mathrm{TiO_2} \rightarrow \mathrm{Ba_2Ti_9O_{20}}$$

This phase transformation in BCT sample is thought to be the reason of the rapid grain growth, and phase transformation accompanied grain growth has been reported. $^{11,12)}$ Concerning the molar volume of the $\rm BaTi_4O_9,\ TiO_2$ and $\rm Ba_2Ti_9O_{20}$ phase, volume reduction of BCT sample is also expected after the reaction. This results in the pore generation which leads to the lower densification.

Fig. 6 shows the microwave dielectric characteristics of the samples sintered at 1390°C for 2 h. The relative permittivity value (ϵ_r) of BTT sample was almost 40 which is higher than that of BCT sample. The quality factor of BTT sample was outstandingly high. It is known that the dielectric permittivity is affected by the composition and density

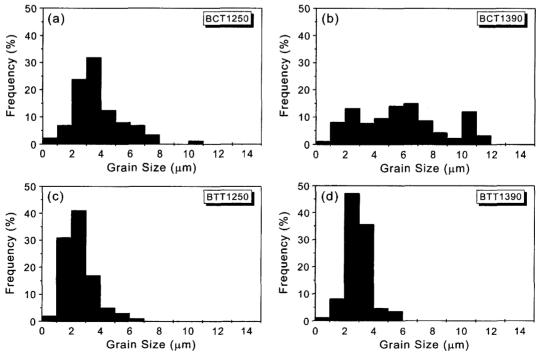


Fig. 5. Grain size distribution of BCT (a, b) and BTT (c, d) specimens sintered at 1250°C (a, c) and 1390°C (b, d) for 2 h.

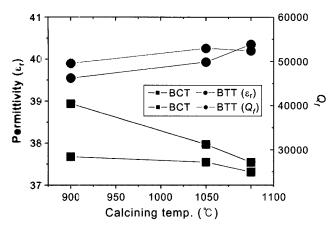


Fig. 6. Dielectric properties of BCT and BTT specimens as a function of calcining temperature.

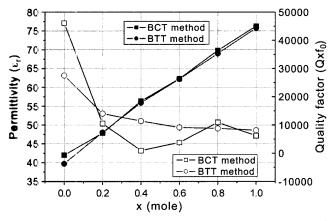


Fig. 7. Dielectric properties of BCT and BTT specimens of BaO-xSm₂O₃-4.5TiO₂ system as a function of x.

while the quality factor is affected by the defects, pores, and second phases etc. Since BTT sample is composed of a single phase with higher density and more homogeneous microstructure than BCT, the dielectric constant and the quality factor of BTT were superior to those of BCT.

The dielectric characteristics of BaO-xSm₂O₃-4.5TiO₂ system are shown in Fig. 7. The ε_r increased linearly from 40 to 77 as the x value increased from 0.0 to 1.0, regardless of the different processing methods. It is because the ε_r values of the secondary phases, i.e. BaTi₄O₉ and Ba₂Ti₉O₂₀, are 40 and 38, respectively, which are very similar to the matrix 1:1: 4 phase and each other. 13-15) However, the quality factor of the samples was affected by the different processing methods. As the x changed from 0 to 0.2, the quality factor decreased greatly. Because the 1:1:4 phase has low quality factor and the BaTi₄O₉ and Ba₂Ti₉O₂₀ phases have high quality factors, the variation of volume fraction of the **phases** with respect to x seems to be the reason of decreased quality factor. In the samples prepared by the BCT method, the quality factor greatly decreased in the range of x=0.2~0.4 since two different kinds of secondary phases of TiO2 and 1:1:4 coexisted. On the other hand, as BaTi₄O₉ phase has higher quality factor than 1:1:4 phase, the decrease in

the volume fraction of $BaTi_4O_9$ phase could have played a role in the decrease of the quality factor. However, the BTT method-derived samples that were close to the stoichiometric composition revealed stabilization in quality factors.

4. Conclusions

In synthesizing Ba₂Ti₉O₂₀ ceramics by different solid state reaction methods of BCT and BTT, BaTi₄O₉ phase was easily formed when BCT method was used, while its formation was suppressed and a single phase of Ba₂Ti₂O₂₀ was obtained when BTT method was used. Because the BaTiO3 precursor provides short diffusion paths of ions, the system revealed less secondary phases during solid state reaction. Therefore, BaTiO₃ and TiO₂ system was considered to be closer to the equilibrium state than BaCO₃ and TiO₂ system. In case of BTT samples, homogeneous and fine grains were observed compared to the case of BCT samples. The grain size distribution of BCT was broader than BTT case. The relative permittivity value (ε_r) and the quality factor of BTT sample were superior to those prepared by the BCT method. In case of $BaO-xSm_2O_3-4.5TiO_2$ system, as observed in Ba₂Ti₉O₂₀ ceramics, the system prepared by BTT method was considered to be closer to the equilibrium state. It is therefore concluded that the BTT method using BaTiO₃ precursor is highly advantageous in BaO-TiO2 containing microwave dielectrics.

REFERENCES

- K. Wakino, "Recent Development of Dielectric Resonator Materials and Filters in Japan," Ferroelectrics, 91 69-86 (1989).
- 2. G. H. Jonker and W. Kwestroo, "The Ternary Systems $BaO-TiO_2-SnO_2$ and $BaO-TiO_2-ZrO_2$," J. Am. Ceram. Soc., **41** [10] 390-94 (1958).
- 3. H. M. O'Bryan and J. Thomson, "Ba $_2$ Ti $_9$ O $_{20}$ Phase Equilibria," J. Am. Ceram. Soc., **66** [1] 66-8 (1983).
- J. M. Wu and H. W. Wang, "Factors Affecting the Formation of Ba₂Ti₉O₂₀," J. Am. Ceram. Soc., 71 [10] 869-75 (1988).
- J. Yu, H. Zhao, Z. Wang, and F. Xia, "Effect of Al₂O₃ and Bi₂O₃ on the Formation Mechanism of Sn-doped Ba₂Ti₉O₂₀," J. Am. Ceram. Soc., 77 [4] 1052-56 (1994).
- S. L. Swartz, T. R. Shrout, W. A. Schulze, and L. E. Cross, "Dielectric Properties of Lead-magnesium Niobate Ceramics," J. Am. Ceram. Soc., 67 [5] 311-14 (1984).
- S. L. Swartz and T. R. Shrout, "Fabracation of Perovskite Lead Magnesium Niobate," Mat. Res. Bull., 17 [10] 1245-50 (1982).
- B. W. Hakki and P. D. Coleman, "A Dielectric Resonator Method of Measuring Inductive Capacities in the Millimeter Range," *IRE Trans. on Microwave Theory Tech.*, MTT-8, 402-10 (1960).
- Y. Kobayashi and M. Katoh, "Microwave of Dielectric Properties of Low-loss Materials by the Dielectric Rod Resonator Method," IEEE Trans. on Microwave Theory Tech.,

- MTT-33, 7 (1985).
- 10. S. Nishigaki, S. Yano, H. Kato, T. Hirai, and T. Nonomura, "BaO-TiO₂-WO₃ Microwave Ceramics and Crystalline BaWO₄," J. Am. Ceram. Soc., **71** [1] C-11-C17 (1988).
- B. C. Kim, S. M. Kim, J. H. Lee, and J. J. Kim, "Effect of Phase Transformation on the Densification of Coprecipitated Nanocrystalline ITO Powders," J. Am. Ceram. Soc., 85 [8] 2083-88 (2002).
- 12. J. H. Lee and Y.-M. Chiang, "Pyrochlore-perovskite Phase Transformation in Highly Homogeneous (Pb,La)(Zr,Sn,Ti) O₃ Powders," J. Mat. Chem., **9** [12] 3107-11 (1999).
- 13. H. M. O'Bryan Jr., J. Thomson, and J. K. Plourde, "A New BaO-TiO₂ Compound with Temperature-stable High Permittivity and Low Microwave Loss," J. Am. Ceram. Soc., 57 [10] 450-53 (1974).
- S. G. Mhaisalkar, D. W. Readey, and S. A. Akbar, "Microwave Dielectric Properties of Doped BaTi₄O₉," J. Am. Ceram. Soc., 74 [8] 1894-98 (1991).
- 15. J. K. Plourde, D. F. Linn, H. M. O'Bryan, Jr., and J. Thomson, Jr., "Ba $_2$ Ti $_9$ O $_{20}$ as a Microwave Dielectric Resonator," J. Am. Ceram. Soc., **58** [9-10] 418-20 (1975).